

December 1997

Radiation Hardened Quad 2-Input Non-Inverting Multiplexer

Features

- QML Qualified Per MIL-PRF-38535 Requirements
- 1.25Micron Radiation Hardened SOS CMOS
- Radiation Environment
 - Latch-up Free Under any Conditions
 - Total Dose 3×10^5 RAD(Si)
 - SEU Immunity $<1 \times 10^{-10}$ Errors/Bit/Day
 - SEU LET Threshold $>100\text{MeV}(\text{mg}/\text{cm}^2)$
- Input Logic Levels ... $V_{IL} = (0.3)(V_{CC})$, $V_{IH} = (0.7)(V_{CC})$
- Output Current $\pm 12\text{mA}$
- Quiescent Supply Current $20\mu\text{A}$
- Propagation Delay 14ns

Applications

- 4-Bit Source Selection
- Data Routing
- High Frequency Switching

Description

The Radiation Hardened ACS157MS is a Quad 2-Channel Non-Inverting Multiplexer which selects four bits of data from one of two sources under the control of a single Select pin. The Output Enable input is active LOW and controls all outputs. When $\bar{E}$ is set HIGH, all outputs are forced LOW, regardless of all other input conditions. All inputs are buffered and the outputs are designed for balanced propagation delay and transition times.

The ACS157MS is fabricated on a CMOS Silicon on Sapphire (SOS) process, which provides an immunity to Single Event Latch-up and the capability of highly reliable performance in any radiation environment. These devices offer significant power reduction and faster performance when compared to ALSTTL types.

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed below must be used when ordering.

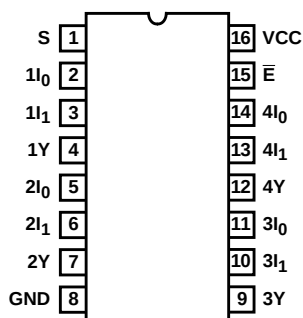
Detailed Electrical Specifications for the ACS157 are contained in SMD 5962-98536. A "hot-link" is provided on our homepage with instructions for downloading. <http://www.intersil.com/data/sm/index.htm>

Ordering Information

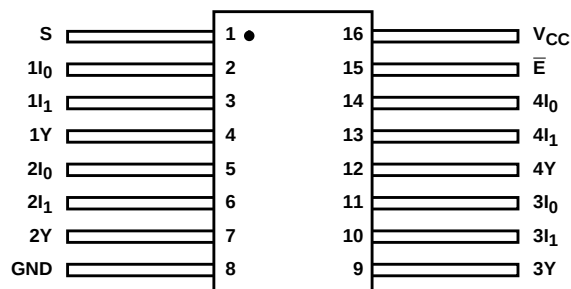
SMD PART NUMBER	INTERSIL PART NUMBER	TEMP. RANGE (°C)	PACKAGE	CASE OUTLINE
5962F9853601VEC	ACS157DMSR-02	-55 to 125	16 Ld SBDIP	CDIP2-T16
N/A	ACS157D/Sample-02	25	16 Ld SBDIP	CDIP2-T16
5962F9853601VXC	ACS157KMSR-02	-55 to 125	16 Ld Flatpack	CDFP4-F16
N/A	ACS157K/Sample-02	25	16 Ld Flatpack	CDFP4-F16
N/A	ACS157HMSR-02	25	Die	N/A

Pinouts

ACS157 (SBDIP)
TOP VIEW



ACS157 (FLATPACK)
TOP VIEW



Die Characteristics

DIE DIMENSIONS:

Size: 2390 μ m x 2390 μ m (94 mils x 94 mils)
 Thickness: 525 μ m $\pm$ 25 μ m (20.6 mils $\pm$ 1 mil)
 Bond Pad: 110 μ m x 110 μ m (4.3 x 4.3 mils)

METALLIZATION: Al

Metal 1 Thickness: 0.7 μ m $\pm$ 0.1 μ m
 Metal 2 Thickness: 1.0 μ m $\pm$ 0.1 μ m

SUBSTRATE POTENTIAL:

Unbiased Insulator

PASSIVATION

Type: Phosphorous Silicon Glass (PSG)
 Thickness: 1.30 μ m $\pm$ 0.15 μ m

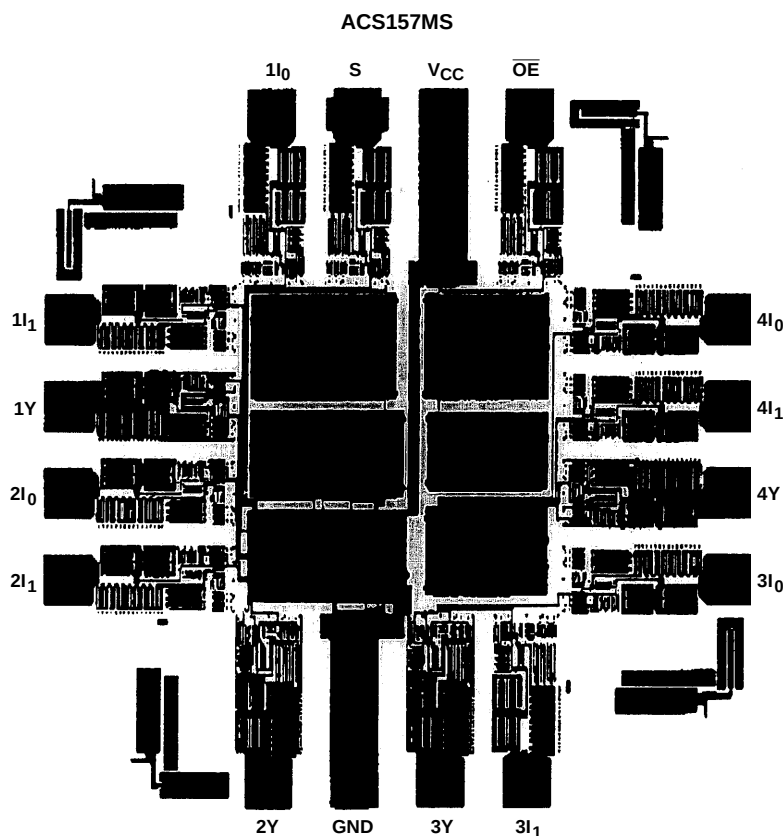
SPECIAL INSTRUCTIONS:

Bond V_{CC} First

ADDITIONAL INFORMATION:

Worst Case Density: <2.0 x 10⁵ A/cm²
 Transistor Count: 150

Metallization Mask Layout



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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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